NSN 5961-01-294-5797

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Inclosure Material:

Plastic

Overall Length:

Between 0.075 inches and 0.100 inches

Overall Diameter:

Between 0.175 inches and 0.205 inches

Internal Configuration:

Junction contact

Mounting Method:

Press fit

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

18.0 collector to emitter voltage/static/base open and 36.0 collector to base voltage/static/emitter open and 2.5 emitter to base voltage,

static, collector open

Current Rating Per Characteristic:

200.00 milliamperes source cutoff current

Power Rating Per Characteristic:

2.5 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

4 ribbon

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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